

Features and Benefits

- 3.5V to 24V Operation
- -40°C to 150°C Superior temperature operation
- CMOS technology
- Low current consumption
- Chopper-stabilized amplifier stage
- Open drain output
- Low sensitivity
- Small Size-SOT23 3L or SIP 3L
- both RoHS compliant packages

Application Examples

- Automotive, Consumer and Industrial
- Solid-state switch
- Brushless DC motor commutation
- Speed detection
- Angular position detection
- Proximity detection
- Current detector

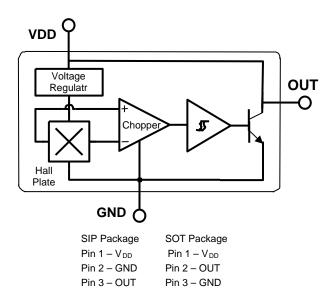


3 pin SOT23 (suffix SO)



3 pin SIP (suffix UA)

Functional Block Diagram





General Descriptions

The SS1104 is a unipolar Hall-effect sensor IC fabricated from CMOS technology. The device integrates a voltage regulator, Hall sensor with dynamic offset cancellation system, small signal amplifier, Schmitt trigger and an open-drain output driver. With suitable output pull up, they can be used with bipolar or CMOS logic circuits.

These Hall-effect switches are monolithic integrated circuits with tighter magnetic specifications, designed to operate continuously over extended temperatures to $+150^{\circ}$ C, and are

more stable with both temperature and supply voltage changes. The unipolar switching characteristic makes these devices ideal for use with a simple bar or rod magnet.

Thanks to its wide operating voltage range and extended choice of temperature range, it is quite suitable for use in automotive, industrial and consumer applications.

The device is delivered in a Small Outline Transistor (SOT) or in a Plastic Single In Line (SIP 3L flat). Both 3-lead packages are RoHS compliant.

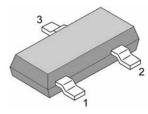
Glossary of Terms

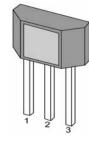
MilliTesla (mT),	Gauss Units of magnetic flux density: $1mT = 10$ Gauss
RoHS	Restriction of Hazardous Substances
Operating Point (B _{OP})	Magnetic flux density applied on the branded side of the package which turns the output
	driver ON ($V_{OUT} = V_{DSon}$)
Release Point (B _{RP})	Magnetic flux density applied on the branded side of the package which turns the output
	driver OFF ($V_{OUT} = high$)



Pin Definitions and Descriptions

SOT Pin №	SIP Pin №	Name	Туре	Function
1	1	VDD	Supply	Supply Voltage pin
2	3	OUT	Output	Open Drain Output pin
3	2	GND	Ground	Ground pin





Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Supply Voltage	VDD	28	V
Supply Current	IDD	50	mA
Output Voltage	VOUT	28	V
Output Current	IOUT	50	mA
Storage Temperature Range	TS	-65 to 170	°C

Absolute maximum ratings

Operating Temperature Range	Symbol	Value	Units
Temperature Suffix "E"	TA	-40 to 85	°C
Temperature Suffix "E"	TA	-40 to 125	°C
Temperature Suffix "L"	TA	-40 to 150	°C

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum- rated conditions for extended periods may affect device reliability.



General Electrical Specifications

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Supply Voltage	VDD	Operating	3.5		24	V
Supply Current	IDD	B < B _{RP}	1.5	2.5	5	mA
Output Saturation Voltage	VDSon	IOUT = 20 mA, B > B _{OP}		0.4	0.5	V
Output Leakage Current	IOFF	$B < B_{RP}$ VOUT = 24V		0.01	10	μΑ
Output Rise Time	tr	$RL = 1k\Omega$, $CL = 20pF$		0.25		μs
Output Fall Time	tf	RL =1k Ω , CL = 20pF		0.25		μs

DC Operating Parameters $T_A = 25^{\circ}$ C, $V_{DD} = 3.5$ V to 24V (unless otherwise specified)

Magnetic Specifications

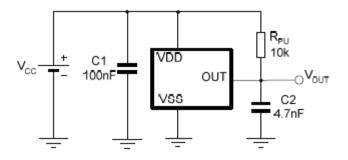
DC Operating Parameters $V_{DD} = 3.5V$ to 24V (unless otherwise specified)

SS1104

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Operating Point	B _{OP}		160	190	220	G
Release Point	B _{RP}	Ta=25°C,Vdd=12V DC	110	150	200	G
Hysteresis	B _{HYS}			40		G

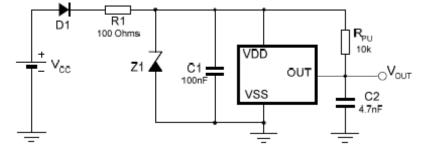
Application Information

Typical Three-Wire Application Circuit





Automotive and Harsh, Noisy Environments Three-Wire Circuit



Application Comments

For proper operation, a 100nF bypass capacitor should be placed as close as possible to the device between the VDD and ground pin. For reverse voltage protection, it is recommended to connect a resistor or a diode in series with the VDD pin.

When using a resistor, three points are important:

- the resistor has to limit the reverse current to 50mA maximum (VCC / R1 $\,$ 50mA)
- the resulting device supply voltage VDD has to be higher than VDD min (VDD = VCC R1.IDD)

- the resistor has to withstand the power dissipated in reverse voltage condition ($PD = VCC^2/R1$)

When using a diode, a reverse current cannot flow and the voltage drop is almost constant (0.7V).

Therefore, a 100 /0.25W resistor for 5V application and a diode for higher supply voltage are recommended. Both solutions provide the required reverse voltage protection.

When a weak power supply is used or when the device is intended to be used in noisy environment, it is recommended that figure 13.3 from the Application Information section is used.

The low-pass filter formed by R1 and C1 and the zener diode Z1 bypass the disturbances or voltage spikes occurring on the device supply voltage VDD. The diode D1 provides additional reverse voltage protection.

ESD Precautions

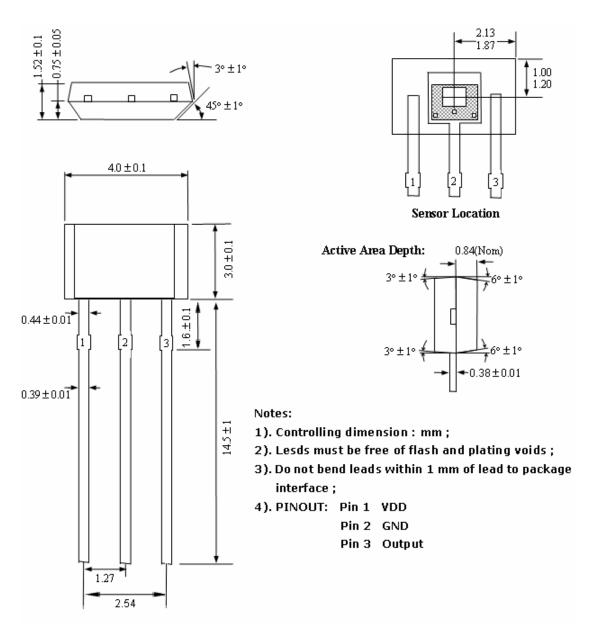
Electronic semiconductor products are sensitive to Electro Static Discharge (ESD).

Always observe Electro Static Discharge control procedures whenever handling semiconductor products.



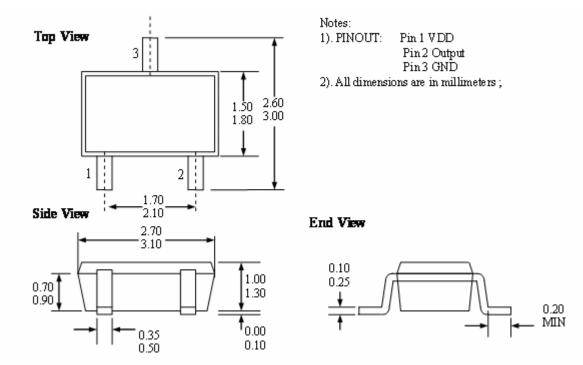
Package Information

Package UA, 3-Pin SIP:





Package LH, 3-Pin SOT-23:



Ordering Information

Part No.	Pb-free	Temperature Code	Package Code	Packing
SS1104ESOT	YES	-40°C to 85°C	SOT-23	7-in. reel, 3000 pieces/ reel
SS1104EUA	YES	-40°C to 85°C	TO-92	Bulk, 1000 pieces/ bag
SS1104KSOT	YES	-40°C to 125°C	SOT-23	7-in. reel, 3000 pieces/ reel
SS1104KUA	YES	-40°C to 125°C	TO-92	Bulk, 1000 pieces/ bag
SS1104LSOT	YES	-40°C to 150°C	SOT-23	7-in. reel, 3000 pieces/ reel
SS1104LUA	YES	-40°C to 150°C	TO-92	Bulk, 1000 pieces/ bag